

NEW CM75DY-24H MITSUBISHI IGBT MODULE CM75DY24H

Model	CM75DY-24H
Brand	MITSUBISHI
Category	MITSUBISHI
Collector-Emitter Voltage (Vces)	1200 V
Nominal Collector Current (Ic)	75 A
Collector-Emitter Sat. Voltage (Vce(sat))	2.30 V (max)
Diode Forward Voltage (Vf)	2.20 V (max)
Total Power Loss (Pt)	270 W (max)
Isolation Voltage (Visol)	2500 Vrms
Turn-off Time (toff)	0.45 μ s (typ)
Gate-Emitter Voltage (Vges)	\pm 20 V (max)
Thermal Resistance (Junction-Case)	0.45 $^{\circ}$ C/W (max)
Module Configuration	Dual / 2-in-1

Note:

Invshop recommends that you inquire with the original factory or its agents about the latest production status and technical information about CM75DY-24H. The product parameters displayed on Invshop are entered by Invshop engineers according to the specifications, and efforts have been made to minimize errors, but we cannot guarantee the complete correctness of the parameters. Please refer to the specification sheet!

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